NSN 5961-00-494-4960

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View Online at https://aerobasegroup.com/nsn/5961-00-494-4960 **Inclosure Material:** Metal **Overall Length:** 0.850 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 90.0 breakdown voltage, collector-to-base, emitter open and 90.0 breakdown voltage, collector-to-emitter, base open and 20.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release4200 professional/industrial association specification

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N/a

Shelf Life:

Unit Of Measure:

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